NSN 5961-00-225-2132

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-225-2132 **Inclosure Material:** Metal **Overall Length:** 1.082 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.437 inches Thread Size: 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 150.0 nonrepetitive peak reverse voltage and 100.0 forward voltage, peak and 100.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 5.00 amperes zero-gate-voltage source current horsepower metric and 2.00 amperes zero-gate-voltage source current torr **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 80131-release 5221 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0